	Type	Hits	Search Text	DBs	Time Stamp
1	IS&R	9627	((257/698,752,758,773-776,781,786) or (257/E23.02,E23.152,E23.194)),CCLS.	USPAT	2068/07/03 11:46
2	IS&R	7215	(257/698,752,758,773-776,781,786) or (257/E23.02.E23.152,E23.194)). CCLS.	OS-PGPUB: USOCR; EPRS: EPO; JPO; DERWENT: IBM_TDB	2008/07/03 12:38
3	IS&R	7378	(438/612,614,618,622,629.637,639,640,666,668,672) CCLS.	USPAT	2008/07/03 13:01
***)\$&R	7201	(438/612,614,618.622,629,637,639.640.666,668,672) .CCLS.	US-POPUB. USOCR: FPRS; EPO: PPO; DERWENT: BM_TDB	2008/07/03 13:01
5	BRS	6343	S56 not SS4	USPAT	2008/07/03
6	BRS	6248	SS7 not SSS	US-PGPUB; USOCR: FPRS; EPO: JPO; DERWENT; IBM_TOB	2008/07/03 13:06
**	BRS	152	(active transistor gate) and ((bond honding) near2 (pad)) and ((mesh meshed) near3 (wire wiring interconnect interconnection layer film))	USPAT	2008/07/03 16:58
8	BRS	135	(active transistor gate) and ((bond bonding) near2 (pad)) and ((mesh meshed) near3 (wire wiring interconnect interconnection layer film))	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	2008/07/03 16:58

	Type	L#	Hits	Search Text	DBs	Time Stamp
****	BRS	1.2	0	((active transistor gate) and ((bond bonding) near2 (pad)) and ((mesh meshed) near3 (wire wiring interconnect interconnection layer film))),clm.	US-PGPUB	2008/07/04 16:51